

Supporting Information

High-Mobility Two-Dimensional Electron Gas in SrGeO₃- and BaSnO₃-Based Perovskite Oxide Heterostructures: *Ab-initio* Study

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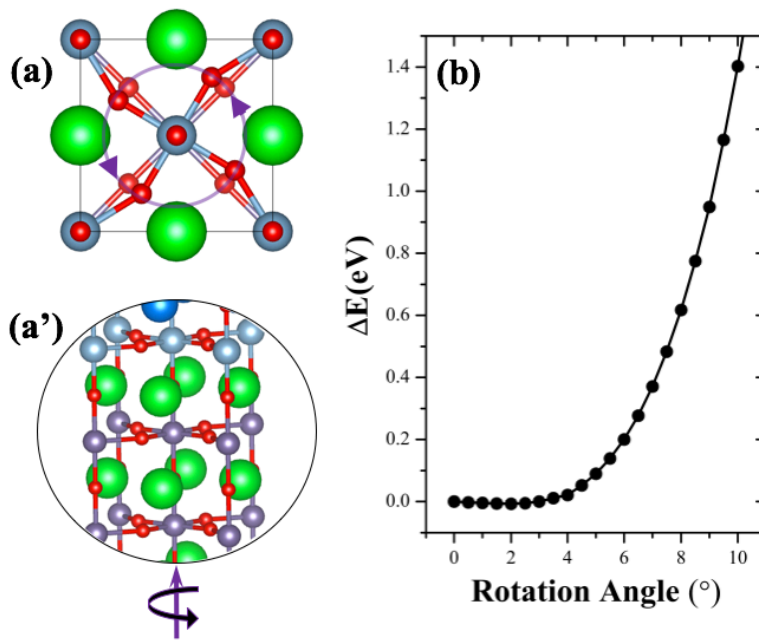


Figure S1. Scheme of LaAlO₃/SrGeO₃ heterostructure with GeO₆ and AlO₆ rotations from (a) top view and (a') side view, and (b) calculated total energy difference ΔE as a function of the rotation angle. ΔE is calculated relative to the total energy of non-rotated structure. All AlO₆ cages in the film and two GeO₆ cages near the interface are rotated.